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Very Large Changes in Bond Length and Bond Angle in a Heavy Group 14 Element Alkyne Analogue by Modification of a Remote Ligand Substituent

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Scheme 1. Schematic Drawing of Ar*, Ar', and Ar'-4-SiMe3

Recent experimental work^{1–8} has resulted in the syntheses and structural characterization of several examples of stable heavier group 14 element alkyne analogues of formula RMMR (R = large aryl or silyl substituent, M = Si, Ge, Sn, Pb). X-ray crystallographic studies have shown that they have a *trans*-bent, planar,^{1–3,7} or almost planar⁸ core arrangement with angles at M that range from 137.44-(4)° (M = Si)⁷ to 94.26(4)° (M = Pb).¹ With the exception of the lead derivative, the M–M distances fall in the range expected for an M–M bond order between 2 and 3. For the lead species Ar*PbPbAr* (Ar* = C₆H₃-2,6-(C₆H₂-2,4,6-*i*-Pr₃)₂, Scheme 1), the Pb–Pb bond length is 3.1881(1) Å and there is a strongly bent (Pb–Pb–C = 94.26(4)°) core structure consistent with the representation



in which there is single-bonding and a nonbonding pairs of electrons at each lead. Calculations by Frenking and co-workers have shown that the Ar* ligand plays a crucial role in stabilizing the observed molecular configuration in comparison to others that would be more stable (by <10 kcal mol⁻¹) with less crowding ligands.⁹ Calculations by Nagase and Takagi¹⁰ for the Ge and Sn species RMMR (R =Ar* or Tbt (Tbt = C_6H_2 -2,4,6-{CH(SiMe_3)_2}_3) predicted structures for Ar*GeGeAr* (Ge–Ge = 2.277 Å, Ge–Ge–C = 123.2°)¹¹ and TbtGeGeTbt (Ge-Ge = 2.231 Å, Ge-Ge-C = 121.8°) that were quite similar to those experimentally measured for Ar'GeGeAr' (Ar' $= C_6H_3-2,6-(C_6H_3-2,6-i-Pr_2)_2^3$, Ge-Ge = 2.2850(6) Å, Ge-Ge-C = $128.27(8)^{\circ}$) and more recently by Tokitoh and co-workers for BbtGeGeBbt (Bbt = C_6H_2 -2,6-{CH(SiMe_3)_2}_2-4-C(SiMe_3)_3, Ge- $Ge = 2.22 \text{ Å avg}, Ge-Ge-C = 131^{\circ} \text{ avg}).^{8}$ These bond distances were in the range observed for the Ge-Ge double bonds in digermenes.12 The stronger bonding in BbtGeGeBbt was rationalized on the basis of a lower Δ_{D-Q} for the GeBbt fragment, which leads to a stronger Ge-Ge interaction.⁸ In contrast, the calculations predicted that a "multiple-bonded" Ar*SnSnAr* should have a more *trans*-bent structure $(Sn-Sn-C = 111.0^\circ, a C-Sn-Sn-C torsion)$ angle of 125.3°) and a relatively long Sn-Sn bond of 2.900 Å. These values differed considerably from those experimentally measured for Ar'SnSnAr' (Sn-Sn = 2.6675(4) Å, Sn-Sn-C = 125.249(2)°). The calculations also predicted that the singly-bonded Ar*SnSnAr* isomer (analogous to the Ar*PbPbAr* structure above) with Sn-Sn = 3.087 Å and $Sn-Sn-C = 99.0^{\circ}$ differed in energy by only 4.8 kcal mol⁻¹ from "multiple-bonded" Ar*SnSnAr*. Seemingly, these large structural changes carry only a small energy



4-SiMe₃-Ar'SnSnAr'-4-SiMe₃ 1

penalty, and this unusual result has been confirmed by calculations on simpler RMMR (M = Si-Pb; $R = H^{13}$ or Me^{14}) models.

We now supply experimental evidence to support this prediction by the synthesis and characterization of the alkyne analogue 4-Me₃-Si-Ar'SnSnAr'-4-SiMe₃ (1). This compound employs the modified terphenyl ligand C_6H_2 -2,6- $(C_6H_3$ -2,6-*i*-Pr₂)₂-4-SiMe₃ (Ar'-4-SiMe₃, Scheme 1) in place of Ar'. This results in a species that has a much longer Sn-Sn distance and a narrower Sn-Sn-C angle than those found in Ar'SnSnAr'.

The ligand precursor 1-I-C₆H₂-2,6-(C₆H₃-2,6-*i*-Pr₂)₂-4-SiMe₃ (**4**) was isolated by the addition of 2 equiv of BrMgC₆H₃-2,6-*i*-Pr₂ (BrMgDipp) to 1-Li-2,6-Cl₂-C₆H₂-4-SiMe₃, with subsequent quenching with I₂ by a standard route¹⁵ (Scheme 2). In a manner similar to the preparation of $[Ar'Li]_2$,¹⁶ **3** was synthesized by reaction of **4** with *n*-BuLi.

Subsequent reaction of **3** with excess SnCl₂ in diethyl ether and crystallization from the same solvent at -20 °C yielded [1-ClSnC₆H₂-2,6-(C₆H₃-2,6-*i*-Pr₂)₂-4-SiMe₃]₂ (**2**). Reduction of **2** with potassium in diethyl ether and subsequent crystallization afforded **1** as dark green, air- and moisture-sensitive crystals.¹⁷ X-ray crystallography showed that **1** has a *trans*-bent structure in the solid state¹⁸ with geometric (Figure 1) parameters that differ dramatically (Figure 2) from those previously reported for Ar'SnSnAr'.

In 1, the Sn–Sn bond length is 3.066(1) Å, which is about 0.4 Å longer than the 2.6675(4) Å in Ar'SnSnAr'. In addition, the Sn–

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Figure 1. Thermal ellipsoidal plot of 1 (30% probability) without H atoms. Selected bond distances (Å) and angles (°): Sn(1)-Sn(1a), 3.066(1); Sn-(1)-C(1), 2.208(5); Si(1)-C(4), 1.878(6); C(1)-Sn(1)-Sn(1a), 99.25(14); C(2)-C(1)-Sn(1), 125.6(4); C(6)-C(1)-Sn(1), 115.0(4); C(2)-C(1)-C(1)-C(1)-Sn(1), 115.0(4); C(2)-C(1)-C(1)-Sn(1), 115.0(4); C(2)-C(1)-Sn(1), 115.0(4); C(2)-Sn(1), 115.0(4); C(2), 115.0(4); C(2)-Sn(1), 115.0(5), 115.0(5); C(2), 11C(6), 118.3(5); C(1)-C(2)-C(7), 121.6(5); C(3)-C(2)-C(7), 118.5(5).



Figure 2. Comparison of core geometries for 4-SiMe₃Ar'SnSnAr'-4-SiMe₃ 1 and Ar'SnSnAr', flanking aryl groups are not shown for clarity.

Sn-C bond angle is 99.25(14)°, a decrease of about 26° in comparison to the 125.24(7)° in Ar'SnSnAr'. Hence, the structural parameters resemble those of $Ar^{PbPb}Ar^{*}$ (Pb-Pb = 3.1881(1)) Å, $Pb-Pb-C = 94.26(4)^{\circ}$) more than those of Ar'SnSnAr' and are consistent with Sn-Sn single bonding. Another striking difference between the solid-state structures of 1 and Ar'SnSnAr' is the perpendicular arrangement of the ligand's central aryl rings relative to the C-Sn-Sn-C in contrast to the parallel orientation in Ar'SnSnAr', where the central aryl rings lie in the plane with the central structural unit. The dihedral angles Sn-Sn-C-C in 1 are 91.04 and -101.08°, but are 176.99° and 3.09° in Ar'SnSnAr', whereas the lead derivative Ar*PbPbAr* exhibits torsional angles of 95.16° and -88.98°.

The UV-vis spectrum of 1 in hexanes displays two strong absorptions at 416 ($\epsilon = 4700 \text{ L} \text{ mol}^{-1} \text{ cm}^{-1}$) and 608 ($\epsilon = 1200 \text{ L}$ mol⁻¹ cm⁻¹) nm and are slightly bathochromically shifted in comparison to those of Ar'SnSnAr' (410 and 597 nm) and Ar*SnSnAr* (409 and 593 nm), suggesting similar, strongly bent structures of the three compounds in solution.

Our results vindicate the theoretical prediction^{10,13,14} that relatively small amounts of energy separate two different bonding modes of the tin analogues of alkynes. Modification of the known terphenyl ligand Ar' by the introduction of SiMe₃ instead of H at the paraposition of the central aryl ring induces a single-bonded structure without alteration of the steric crowding near the tin center. Preliminary theoretical data on model moieties MC₆H₄-4-SiMe₃ and MC_6H_5 (M = Ge, Sn) indicate about a 2 kcal mol⁻¹ difference in their Δ_{D-Q} energies that, when added together in the dimerized product, results in a 4 kcal mol⁻¹ difference.¹⁹ However it should be borne in mind that these energy differences are sufficiently small to be in the range of packing forces.

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Supporting Information Available: X-ray data (CIF) for 1. This material is available free of charge via the Internet at http://www.pubs.acs.org.

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- (16) Schiemenz, B.; Power, P. P. Angew. Chem., Int. Ed. Engl. 1996, 35, 2150. (17) At room temperature and under strictly anhydrous and anaerobic condi-
- tions, a solution of 0.850 g (1.36 mmol) [1-ClSn-C₆H₂-2,6-(C₆H₃-2,6-i- $Pr_{2/2}$ -4-SiMe₃]₂ (prepared in a fashion similar to previously reported procedures)⁵ in diethyl ether (25 mL) was added to a diethyl ether suspension of 0.059 g (1.51 mmol) of finely dispersed potassium with rapid stirring. The reaction mixture quickly adopted a deep green color, and stirring was continued for 24 h, after which the precipitated material and unreacted potassium were allowed to settle. The solution was filtered through a filter-tipped cannula and concentrated in vacuo to incipient crystallization (ca. 10 mL). Storage at -20 °C yielded 0.41 g (0.328 mmol, 48% yield) of dichroic green-dark orange crystals of **1**•Et₂O. Anal. Calcd for **1**•Et₂O C₇₀H₁₀₀OSi₂Sn₂: C, 67.20; H, 8.06. Found: C, 66.79; H, 8.22. for 1-Et_2O C₇₀H₁₀₀OS₁₅Sn₂: C, 67.20; H, 8.06. Found: C, 66.79; H, 8.22. Mp 183–185 dec. UV – vis λ_{max} (nm, ϵ [L mol⁻¹cm⁻¹]): 416 (4700), 608 (1200). ¹H NMR (C₆D₆, 599.814 MHz, 25 °C): -0.28 (s, 18H, (CH₃)₃Si), 1.12 (t, 6H, (CH₃CH₂)₂O), 1.16 (d, 24H, ³J_{HH} = 6.8 Hz, o-CH-(CH₃)(CH₃)), 1.38 (d, 24H, ³J_{HH} = 6.8 Hz, o-CH(CH₃)(CH₃)), 2.94 (septet, 8H, ³J_{HH} = 6.8 Hz, o-CH(CH₃)(CH₃)), 3.27 (q, 4H, (CH₅CH₂)₂O), 7.07 (d, 8H, ³J_{HH} = 6.7 Hz, m-Dipp), 7.17 (t, 4H, ³J_{HH} = 6.7 Hz, p-Dipp), 7.98 (s, 44H, m-C₆H₂Si(CH₃)), ¹³C{1H} (C₆D₆, 150.823 MHz, 25 °C): -0.6 ((H₃C)Si), 15.5 ((CH₃CH₂)₂O), 26.9 ((CH₄CH₃)(CH₃)), 25.2 (cH-(CH₃)(CH₃)), ³S₂ (CH(CH₃)(CH₃)), ¹²S₂ (CH₂-Dipo)). $\begin{array}{l} \text{(CH}_3(\mathcal{H}_3), 35.9 \ (CH(\mathcal{CH}_3)(\mathcal{CH}_3)), 65.9 \ ((\mathcal{CH}_3(\mathcal{CH}_3)), 52.3 \ (cH_1), 52.3 \ (cH_2)_{2}(\mathcal{O}), 125.2 \ (p-\text{Lopp}), 127.9 \ (m-\text{Dipp}), 138.0 \ (m-\text{Ce}_{H2}), 141.2 \ (o-\text{Dipp}), 143.2 \ (p-\text{Ce}_{H2}), 151.1 \ (i-\text{Dipp}), 161.4 \ (o-\text{Ce}_{H2}), 174.6 \ (i-\text{Ce}_{H2}). \ ^{29}\text{Si}^{1}\text{H} \ (C_6\text{De}, 119.165 \ \text{MHz}, 25 \ ^{\circ}\text{C}): \ -4.2. \ ^{119}\text{Sn}^{1}\text{H} \ (C_6\text{De}, 223.671 \ \text{MHz}, 25 \ ^{\circ}\text{C}): \ \text{no signal} \end{array}$ observed.
- (18) Crystal data for 1·Et₂O at 90 K with Mo K α ($\lambda = 0.71073$ Å): a = 11.605(3) Å, b = 24.573(5) Å, c = 12.733(3) Å, $\beta = 114.407(4)^{\circ}$, V = 3306.5(12) Å³, M = 1251.06 g mol⁻¹, $\beta_{calcd} = 1.257$ Mg m⁻³, F(000) = 1312, monoclinic, space group P2(1)/c, Z = 2, R1 = 0.0557 for 3272 (I > 2(I)) data, wR2 = 0.1246 for all 5975 data. Equipment: Bruker SMADT1000 CCD write Absenting correction profession for the set of th SMART1000 CCD system. Absorption correction was performed using SADABS.^{18a} The structure was solved by direct methods (SHELXS-97), and nonhydrogen atoms were refined anisotropically (full-matrix least-squares on F^2 , SHELXL-97).^{18c} (a) Sheldrick G. M. *SADABS*, version 2.10; Universität Göttingen: Göttingen, Germany, 2003. (b) Sheldrick, G. M. *Acta Crystallogr.* **1990**, *A46*, 467. (c) Sheldrick, G. M. *SHELXS*-97 and *SHELXL-97*; Universität Göttingen: Göttingen, Germany, 1997. (19) Brynda, M. A.; Fischer, R. C.; Power, P. P. Unpublished work.

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